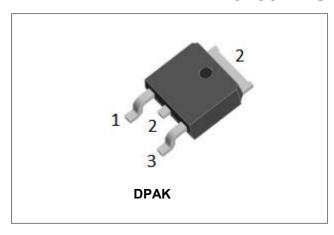






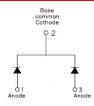
MBRD20100CT SCHOTTKY RECTIFIER



Features

- 150℃ T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =105°C, rectangular wave form	10(peg leg) 20(peg device)	Α
Peak One Cycle Non-Repetitive Surge Current(peg leg)	I _{FSM}	8.3 ms, half Sine pulse	120	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V _{F1}	@ 10A, Pulse, T _J = 25 °C	0.75	0.90	V
(per leg) *	V _{F2}	@ 10A, Pulse, T _J = 125 °C	0.64	0.84	V
Reverse Current (per leg) *	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.006	1.0	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	1	6.0	mA
Junction Capacitance(per leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$		250	pF

^{*} Pulse width < 300 µs, duty cycle < 2%

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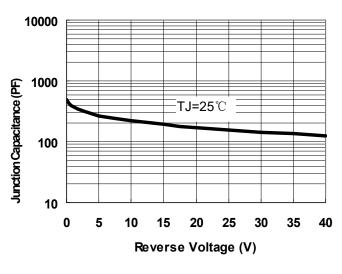




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to + 150	°C
Typical Thermal Resistance Junction to Case(per leg)	R _θ JC	-	3.5	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

Ratings and Characteristics Curves



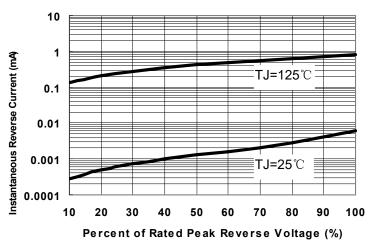


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

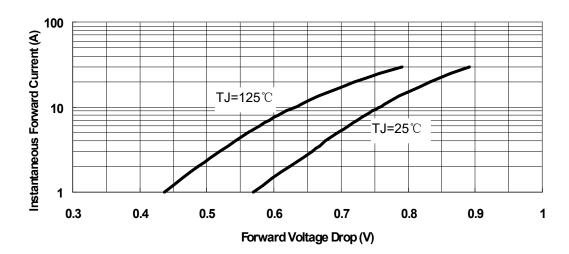


Fig.3-Typical Instantaneous Forward Voltage Characteristics

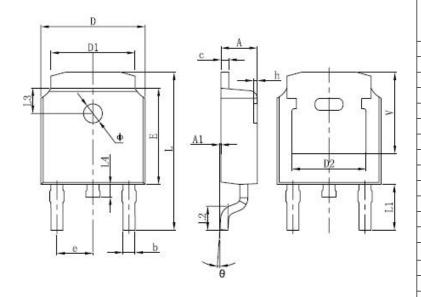
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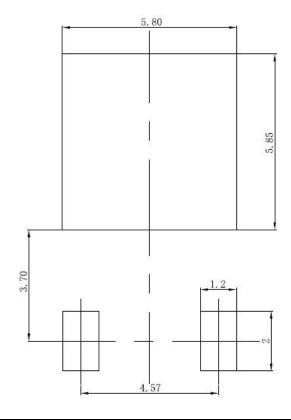


Mechanical Dimensions DPAK



SYMBOL	Dimensions in Millimeters		Dimensions in Inches		
STWIDOL					
	Min.	Max.	Min.	Max.	
Α	2.20	2.40	0.086	0.094	
A 1	0	0.13	0	0.005	
b	0.635	0.889	0.025	0.035	
С	0.460	0.889	0.018	0.035	
D	6.50	6.70	0.250	0.265	
D1	4.95	5.46	0.195	0.215	
D2	4.32 REF.		0.170 REF.		
E	6.00	6.20	0.235	0.245	
е	2.286 BSC		0.090 BSC		
L	9.398	10.414	0.370	0.410	
L1	1.778 REF.		0.108 REF.		
L2	1.40	1.78	0.055	0.07	
L3	1.60 REF.		0.063 REF.		
L4	0.60	1.02	0.024	0.040	
Φ	1.10	1.30	0.043	0.051	
Θ	0°	10°	0°	10°	
h	0	0.30	0	0.012	
V	5.21 REF.		0.205	REF.	

Suggested PCB Prinfoot Layout DPAK(mm)



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Ordering Information

Device	Package	Shipping
MBRD20100CT	DPAK (Pb-Free)	2500pcs / reel
MBRD20100CTTR	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel Packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 MBR
 = Device Type

 D
 = Package type

 20
 = Forward Current (20A)

 100
 = Reverse Voltage (100V)

 CT
 = Configuration

 SSG
 = SSG

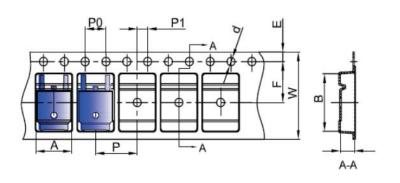
 YY
 = Year

WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification DPAK



SYMBOL	Millimeters		
STIVIDOL	Min.	Max.	
Α	6.80	7.00	
В	10.40	10.60	
С	2.60	2.80	
d	Ф1.45	Ф1.65	
E	1.65	1.85	
F	7.40	7.60	
P0	3.90	4.10	
Р	7.90	8.10	
P1	1.90	2.10	
W	15.90	16.30	

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